

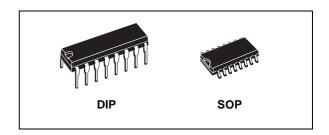


8 CHANNEL DATA SELECTOR

- 3-STATE OUTPUT
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- QUIESCENT CURRENT SPECIF. UP TO 20V
- 5V, 10V AND 15V PARAMETRIC RATINGS
- SV, TOV AND TOV PARAMETRIC RATINGS
 INPUT LEAKAGE CURRENT
- I_I = 100nA (MAX) AT V_{DD} = 18V T_A = 25°C
 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B "STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"



HCF4512B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages.

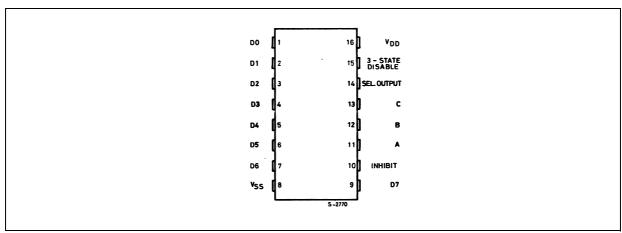


ORDER CODES

| PACKAGE | TUBE | T&R |
|---------|------------|---------------|
| DIP | HCF4512BEY | |
| SOP | HCF4512BM1 | HCF4512M013TR |

HCF4512B is an 8-channel data selector featuring a three-state output that can interface directly with, and drive, data lines of bus oriented systems.

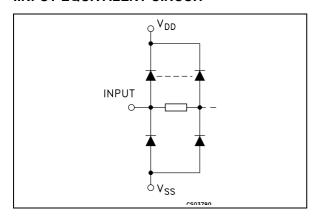
PIN CONNECTION



October 2002 1/9

HCF4512B

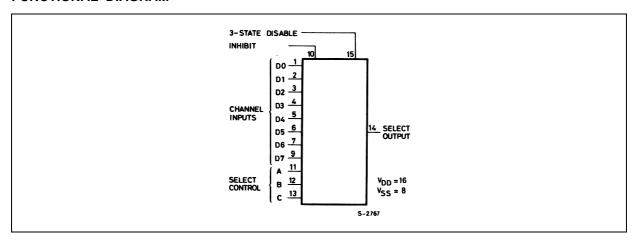
IINPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

| PIN No | SYMBOL | NAME AND FUNCTION |
|---------------------------|--------------------|-------------------------|
| 1, 2, 3, 4, 5, 6, 7, 9 | D0 to D7 | Channel Inputs |
| 11, 12, 13 | A, B, C | Select Control |
| 10 | INHIBIT | Inhibit Output |
| 15 | 3-STATE DISABLE | 3 State Disable Output |
| 14 | SEL OUT- PUT | Select Output |
| 8 | V_{SS} | Negative Supply Voltage |
| 16 | V_{DD} | Positive Supply Voltage |

FUNCTIONAL DIAGRAM

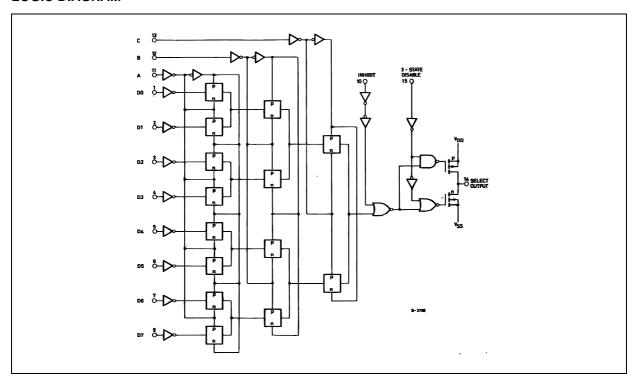


TRUTH TABLE

| SE | SELECT CONTROL | | INILIIDIT | 2 STATE DISABLE | SELECT OUTDUT |
|----|----------------|---|-----------|-----------------|---------------|
| Α | В | С | INHIBIT | 3-STATE DISABLE | SELECT OUTPUT |
| L | L | L | L | L | D0 |
| Н | L | L | L | L | D1 |
| L | Н | L | L | L | D2 |
| Н | Н | L | L | L | D3 |
| L | L | Н | L | L | D4 |
| Н | L | Н | L | L | D5 |
| L | Н | Н | L | L | D6 |
| Н | Н | Н | L | L | D7 |
| Х | Х | Х | Н | L | 0 |
| Х | Х | Х | Х | Н | Z |

X : Don't Care Z : High Impedance

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|------------------|---|-------------------------------|------|
| V _{DD} | Supply Voltage | -0.5 to +22 | V |
| V _I | DC Input Voltage | -0.5 to V _{DD} + 0.5 | V |
| I _I | DC Input Current | ± 10 | mA |
| P _D | Power Dissipation per Package | 200 | mW |
| | Power Dissipation per Output Transistor | 100 | mW |
| T _{op} | Operating Temperature | -55 to +125 | °C |
| T _{stg} | Storage Temperature | -65 to +150 | °C |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V_{SS} pin voltage.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit |
|-----------------|-----------------------|----------------------|------|
| V_{DD} | Supply Voltage | 3 to 20 | V |
| V _I | Input Voltage | 0 to V _{DD} | V |
| T _{op} | Operating Temperature | -55 to 125 | °C |

DC SPECIFICATIONS

| | | | Test Con | dition | | | | | Value | | | | |
|------------------|-----------------------------------|------------------|----------------|--------------------------------|-----------------|-----------------------|-------------------|------|-------------|------|--------------|------|------|
| Symbol Parameter | | V _I V | V _O | V _o I _o | V _{DD} | T _A = 25°C | | С | -40 to 85°C | | -55 to 125°C | | Unit |
| | | (V) | (V) | (μ A) | | Min. | Тур. | Max. | Min. | Max. | Min. | Max. | |
| ΙL | Quiescent Current | 0/5 | | | 5 | | 0.04 | 5 | | 150 | | 150 | |
| | | 0/10 | | | 10 | | 0.04 | 10 | | 300 | | 300 | ^ |
| | | 0/15 | | | 15 | | 0.04 | 20 | | 600 | | 600 | μΑ |
| | | 0/20 | | | 20 | | 0.08 | 100 | | 3000 | | 3000 | |
| V _{OH} | High Level Output | 0/5 | | <1 | 5 | 4.95 | | | 4.95 | | 4.95 | | |
| | Voltage | 0/10 | | <1 | 10 | 9.95 | | | 9.95 | | 9.95 | | V |
| | | 0/15 | | <1 | 15 | 14.95 | | | 14.95 | | 14.95 | | |
| V _{OL} | Low Level Output | 5/0 | | <1 | 5 | | 0.05 | | | 0.05 | | 0.05 | |
| | Voltage | 10/0 | | <1 | 10 | | 0.05 | | | 0.05 | | 0.05 | V |
| | | 15/0 | | <1 | 15 | | 0.05 | | | 0.05 | | 0.05 | |
| V _{IH} | High Level Input | | 0.5/4.5 | <1 | 5 | 3.5 | | | 3.5 | | 3.5 | | |
| | Voltage | | 1/9 | <1 | 10 | 7 | | | 7 | | 7 | | V |
| | | | 1.5/13.5 | <1 | 15 | 11 | | | 11 | | 11 | | |
| V _{IL} | Low Level Input | | 4.5/0.5 | <1 | 5 | | | 1.5 | | 1.5 | | 1.5 | |
| | Voltage | | 9/1 | <1 | 10 | | | 3 | | 3 | | 3 | V |
| | | | 13.5/1.5 | <1 | 15 | | | 4 | | 4 | | 4 | |
| I _{OH} | Output Drive | 0/5 | 2.5 | <1 | 5 | -1.36 | -3.2 | | -1.1 | | -1.1 | | |
| | Current | 0/5 | 4.6 | <1 | 5 | -0.44 | -1 | | -0.36 | | -0.36 | | A |
| | | 0/10 | 9.5 | <1 | 10 | -1.1 | -2.6 | | -0.9 | | -0.9 | | mA |
| | | 0/15 | 13.5 | <1 | 15 | -3.0 | -6.8 | | -2.4 | | -2.4 | | |
| I _{OL} | Output Sink | 0/5 | 0.4 | <1 | 5 | 0.44 | 1 | | 0.36 | | 0.36 | | |
| | Current | 0/10 | 0.5 | <1 | 10 | 1.1 | 2.6 | | 0.9 | | 0.9 | | mΑ |
| | | 0/15 | 1.5 | <1 | 15 | 3.0 | 6.8 | | 2.4 | | 2.4 | | |
| lı | Input Leakage Current | 0/18 | Any In | put | 18 | | ±10 ⁻⁵ | ±0.1 | | ±1 | | ±1 | μΑ |
| l _{OZ} | 3-State Output Leakage Current | 0/18 | 0/18 | _ | 18 | | ±10 ⁻⁴ | ±0.4 | | ±12 | | ±12 | μΑ |
| CI | Input Capacitance | | Any In | put | | | 5 | 7.5 | | | | | pF |

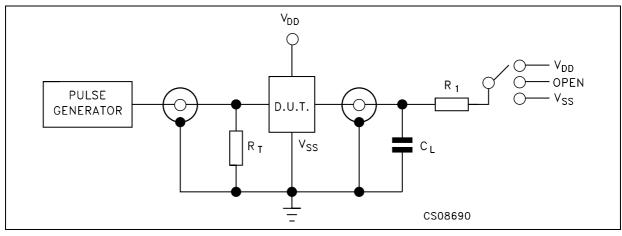
The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD} =5V, 2V min. with V_{DD} =10V, 2.5V min. with V_{DD} =15V

$\textbf{DYNAMIC ELECTRICAL CHARACTERISTICS} \ (T_{amb} = 25 ^{\circ}\text{C}, \ \ C_{L} = 50 \text{pF}, \ R_{L} = 200 \text{K}\Omega, \ \ t_{f} = t_{f} = 20 \ \text{ns})$

| | _ | | Test Condition | , | ') | Unit | |
|-----------------------------------|------------------------|---------------------|----------------|------|------------|------|----|
| Symbol | Parameter | V _{DD} (V) | | Min. | Тур. | Max. | |
| t _{PHL} t _{PLH} | Propagation Delay Time | 5 | | | 140 | 280 | |
| | Inhibit to Output | 10 | | | 70 | 140 | ns |
| | | 15 | | | 50 | 100 | |
| t _{PHL} t _{PLH} | Propagation Delay Time | 5 | | | 200 | 400 | |
| | "A" select to Output | 10 | | | 85 | 170 | ns |
| | | 15 | | | 60 | 120 | |
| t _{PHL} t _{PLH} | Propagation Delay Time | 5 | | | 180 | 360 | |
| | Data to Output | 10 | | | 75 | 150 | ns |
| | | 15 | | | 55 | 110 | |
| t _{PZL} t _{PLZ} | 3-State Disable Delay | 5 | | | 60 | 120 | |
| $t_{PHZ} t_{PZH}$ | Time | 10 | | | 30 | 60 | ns |
| | | 15 | | | 20 | 40 | |
| t _{THL} t _{TLH} | Transition Time | 5 | | | 100 | 200 | |
| | | 10 | | | 50 | 100 | ns |
| | | 15 | | | 40 | 80 | |

^(*) Typical temperature coefficient for all V_{DD} value is 0.3 %/°C.

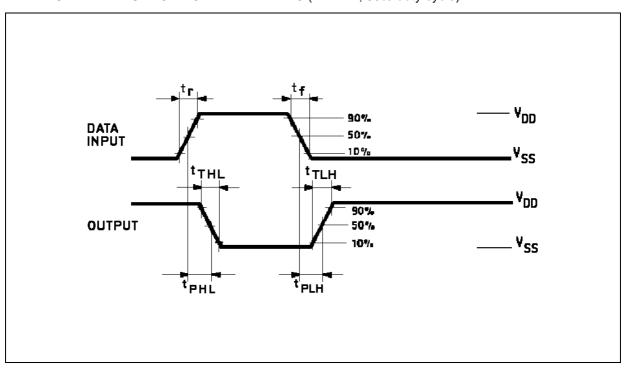
TEST CIRCUIT



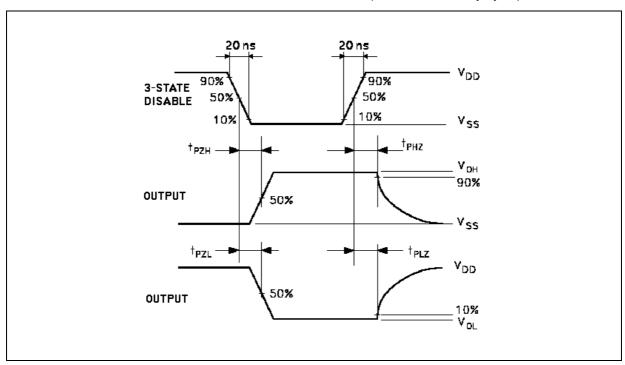
| TEST | SWITCH |
|-------------------------------------|-----------------|
| t _{PLH} , t _{PHL} | Open |
| t _{PZL} , t _{PLZ} | V_{DD} |
| t _{PZH} , t _{PHZ} | V _{SS} |

 C_L = 50pF or equivalent (includes jig and probe capacitance) R_L = 200K Ω R_T = Z_{OUT} of pulse generator (typically 50 Ω)

WAVEFORM 1: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)

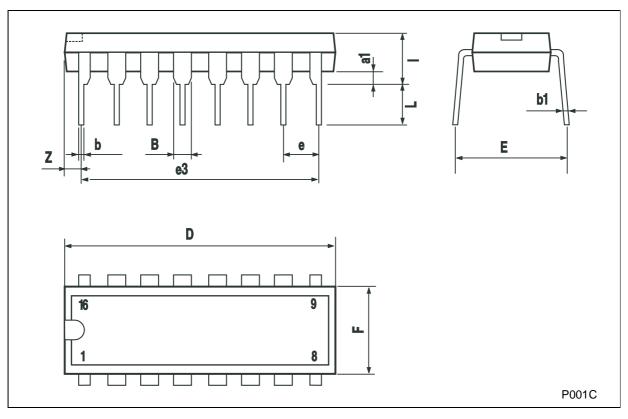


WAVEFORM 2: OUTPUT ENABLE AND DISABLE TIMES (f=1MHz; 50% duty cycle)



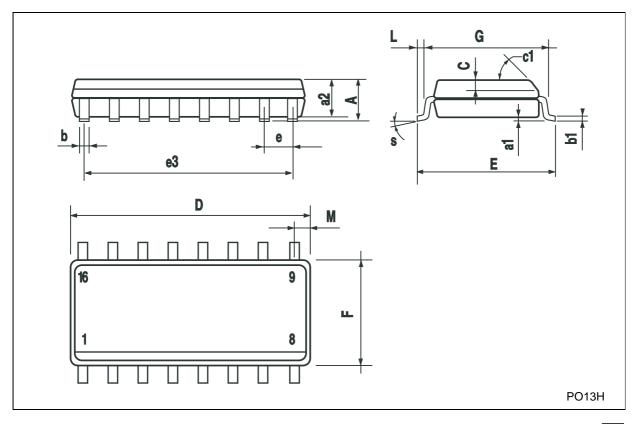
Plastic DIP-16 (0.25) MECHANICAL DATA

| DIM | | mm. | | | | |
|------|------|-------|------|-------|-------|-------|
| DIM. | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| a1 | 0.51 | | | 0.020 | | |
| В | 0.77 | | 1.65 | 0.030 | | 0.065 |
| b | | 0.5 | | | 0.020 | |
| b1 | | 0.25 | | | 0.010 | |
| D | | | 20 | | | 0.787 |
| E | | 8.5 | | | 0.335 | |
| е | | 2.54 | | | 0.100 | |
| e3 | | 17.78 | | | 0.700 | |
| F | | | 7.1 | | | 0.280 |
| I | | | 5.1 | | | 0.201 |
| L | | 3.3 | | | 0.130 | |
| Z | | | 1.27 | | | 0.050 |



SO-16 MECHANICAL DATA

| DIM | | mm. | | | inch | |
|------|------|------|-------|--------|-------|-------|
| DIM. | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| А | | | 1.75 | | | 0.068 |
| a1 | 0.1 | | 0.2 | 0.003 | | 0.007 |
| a2 | | | 1.65 | | | 0.064 |
| b | 0.35 | | 0.46 | 0.013 | | 0.018 |
| b1 | 0.19 | | 0.25 | 0.007 | | 0.010 |
| С | | 0.5 | | | 0.019 | |
| c1 | | | 45° | (typ.) | | |
| D | 9.8 | | 10 | 0.385 | | 0.393 |
| E | 5.8 | | 6.2 | 0.228 | | 0.244 |
| е | | 1.27 | | | 0.050 | |
| e3 | | 8.89 | | | 0.350 | |
| F | 3.8 | | 4.0 | 0.149 | | 0.157 |
| G | 4.6 | | 5.3 | 0.181 | | 0.208 |
| L | 0.5 | | 1.27 | 0.019 | | 0.050 |
| M | | | 0.62 | | | 0.024 |
| S | | | 8° (I | max.) | | • |



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